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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

FAIRCHILD SEMICONDUCTOR®

September 2003

FDG6332C

20V N & P-Channel PowerTrench® MOSFETs

General Description

The N & P-Channel MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

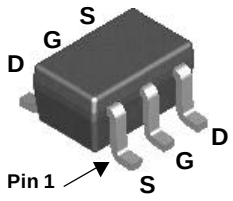
These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive TSSOP-8 and SSOP-6 packages are impractical.

Applications

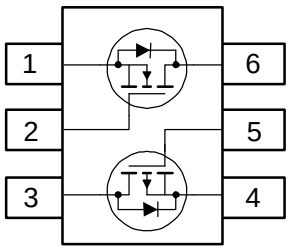
- DC/DC converter
- Load switch
- LCD display inverter

Features

- **Q1** 0.7 A, 20V. $R_{DS(ON)}$ = 300 mΩ @ V_{GS} = 4.5 V
  $R_{DS(ON)}$ = 400 mΩ @ V_{GS} = 2.5 V
- **Q2** –0.6 A, –20V. $R_{DS(ON)}$ = 420 mΩ @ V_{GS} = –4.5 V
  $R_{DS(ON)}$ = 630 mΩ @ V_{GS} = –2.5 V
- Low gate charge
- High performance trench technology for extremely low $R_{DS(ON)}$
- SC70-6 package: small footprint (51% smaller than SSOT-6); low profile (1mm thick)



SC70-6



Complementary

Absolute Maximum Ratings

T_A=25°C unless otherwise noted

Symbol	Parameter	Q1	Q2	Units
V_{DSS}	Drain-Source Voltage	20	–20	V
V_{GSS}	Gate-Source Voltage	±12	±12	V
I_D	Drain Current – Continuous (Note 1)	0.7	–0.6	A
	– Pulsed	2.1	–2	
P_D	Power Dissipation for Single Operation (Note 1)	0.3		W
T_J, T_{STG}	Operating and Storage Junction Temperature Range	–55 to +150		°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1)	415	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.32	FDG6332C	7''	8mm	3000 units

Electrical Characteristics

T_A = 25°C unless otherwise noted

Symbol	Parameter		Test Conditions		Min	Typ	Max	Units
Off Characteristics								
BV_{DSS}	Drain–Source Breakdown Voltage		V_{GS} = 0 V, I_D = 250 µA V_{GS} = 0 V, I_D = –250 µA	**Q1** **Q2**	20 –20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient		I_D = 250 µA,Ref. to 25°C I_D = –250 µA,Ref. to 25°C	**Q1** **Q2**		14 –14		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current		V_{DS} = 16 V, V_{GS} = 0 V V_{DS} = –16 V, V_{GS} = 0 V	**Q1** **Q2**			1 –1	µA
I_{GSSF} /I_{GSSR}	Gate–Body Leakage, Forward		V_{GS} = ± 12 V, V_{DS} = 0 V				±100	nA
I_{GSSF} /I_{GSSR}	Gate–Body Leakage, Reverse		V_{GS} = ± 12V , V_{DS} = 0 V				±100	nA
On Characteristics (Note 2)								
$V_{GS(th)}$	Gate Threshold Voltage	**Q1**	V_{DS} = V_{GS}, I_D = 250 µA		0.6	1.1	1.5	V
		Q2	V_{DS} = V_{GS}, I_D = –250 µA		-0.6	–1.2	–1.5	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	**Q1** **Q2**	I_D = 250 µA,Ref. To 25°C I_D = –250 µA,Ref. to 25°C			–2.8 3		mV/°C
$R_{DS(on)}$	Static Drain–Source On–Resistance	**Q1**	V_{GS} = 4.5 V, I_D =0.7 A V_{GS} = 2.5 V, I_D =0.6 A V_{GS} = 4.5 V, I_D =0.7A,T_J=125°C			180 293 247	300 400 442	mΩ
		Q2	V_{GS} = –4.5 V, I_D = –0.6 A V_{GS} = –2.5 V, I_D = –0.5 A V_{GS}=–4.5 V, I_D =–0.6 A,T_J=125°C			300 470 400	420 630 700	
g_{FS}	Forward Transconductance	**Q1**	V_{DS} = 5 V I_D = 0.7 A			2.8		S
		Q2	V_{DS} = –5 V I_D = –0.6A			1.8		
$I_{D(on)}$	On–State Drain Current	**Q1**	V_{GS} = 4.5 V, V_{DS} = 5 V		1			A
		Q2	V_{GS} = –4.5 V, V_{DS} = –5 V		–2			
Dynamic Characteristics								
C_{iss}	Input Capacitance	**Q1**	V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz			113		pF
		Q2	V_{DS}=–10 V, V_{GS}= 0 V, f=1.0MHz			114		
C_{oss}	Output Capacitance	**Q1**	V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz			34		pF
		Q2	V_{DS}=–10 V, V_{GS}= 0 V, f=1.0MHz			24		
C_{rss}	Reverse Transfer Capacitance	**Q1**	V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz			16		pF
		Q2	V_{DS}=–10 V, V_{GS}= 0 V, f=1.0MHz			9		
Switching Characteristics (Note 2)								
$t_{d(on)}$	Turn–On Delay Time	**Q1**	For **Q1**: V_{DS} =10 V, I_D= 1 A V_{GS}= 4.5 V, R_{GEN} = 6 Ω For **Q2**: V_{DS} =–10 V, I_D= –1 A V_{GS}= –4.5 V, R_{GEN} = 6 Ω			5	10	ns
		Q2				5.5	11	
t_r	Turn–On Rise Time	**Q1**				7	15	ns
		Q2				14	25	
$t_{d(off)}$	Turn–Off Delay Time	**Q1**				9	18	ns
		Q2				6	12	
t_f	Turn–Off Fall Time	**Q1**				1.5	3	ns
		Q2				1.7	3.4	
Q_g	Total Gate Charge	**Q1**	For **Q1**: V_{DS} =10 V, I_D= 0.7 A V_{GS}= 4.5 V, R_{GEN} = 6 Ω For **Q2**: V_{DS} =–10 V, I_D= –0.6 A V_{GS}= –4.5 V, R_{GEN} = 6 Ω			1.1	1.5	nC
		Q2				1.4	2	
Q_{gs}	Gate–Source Charge	**Q1**				0.24		nC
		Q2				0.3		
Q_{gd}	Gate–Drain Charge	**Q1**				0.3		nC
		Q2				0.4		

Electrical Characteristics

T_A = 25°C unless otherwise noted

Symbol	Parameter		Test Conditions		Min	Typ	Max	Units
Drain–Source Diode Characteristics and Maximum Ratings								
I_S	Maximum Continuous Drain–Source Diode Forward Current			**Q1**			0.25	A
				Q2			–0.25	
V_{SD}	Drain–Source Diode Forward Voltage	**Q1**	V_{GS} = 0 V, I_S = 0.25 A (Note 2)			0.74	1.2	V
		Q2	V_{GS} = 0 V, I_S = –0.25 A (Note 2)			–0.77	–1.2	

Notes:

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. $R_{\theta JA}$ = 415°C/W when mounted on a minimum pad of FR-4 PCB in a still air environment.

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

Typical Characteristics: N-Channel

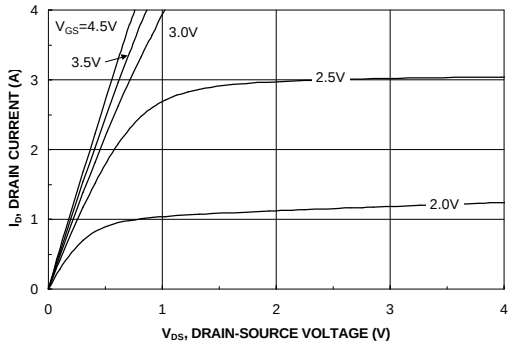


Figure 1. On-Region Characteristics.

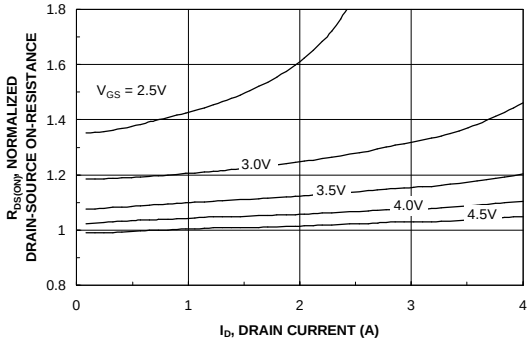


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

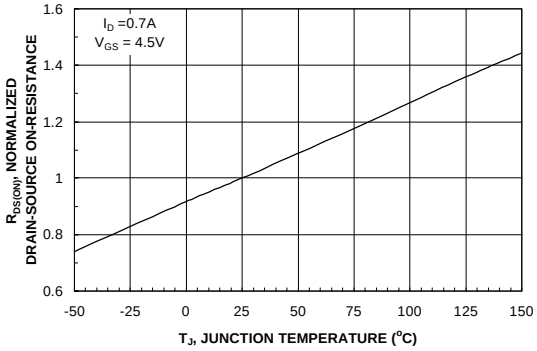


Figure 3. On-Resistance Variation with Temperature.

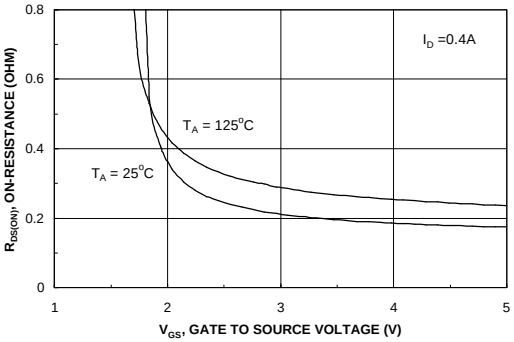


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

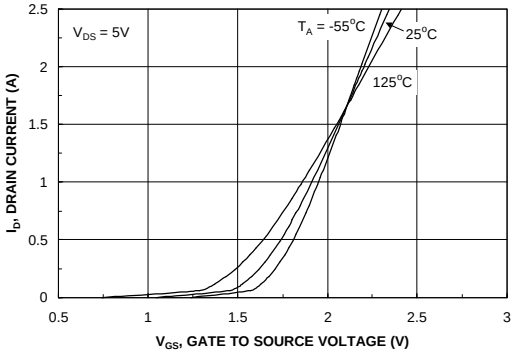


Figure 5. Transfer Characteristics.

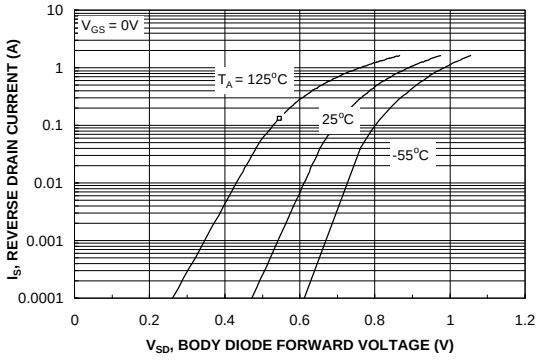


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics: N-Channel

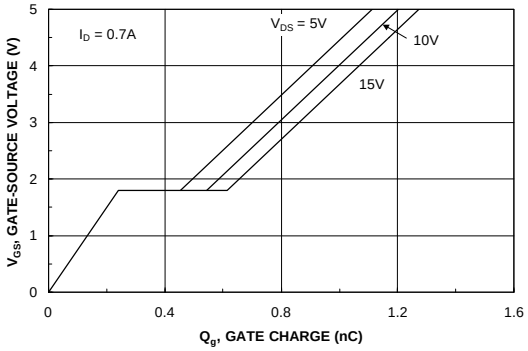


Figure 7. Gate Charge Characteristics.

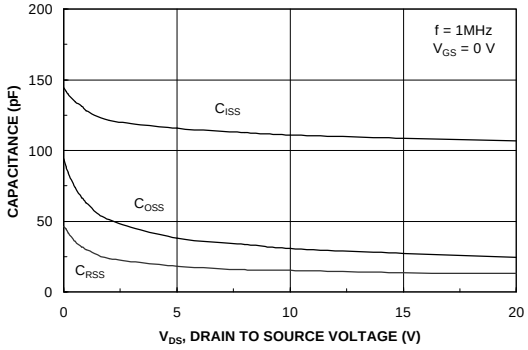


Figure 8. Capacitance Characteristics.

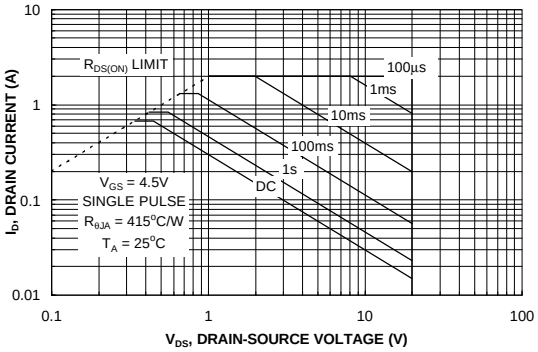


Figure 9. Maximum Safe Operating Area.

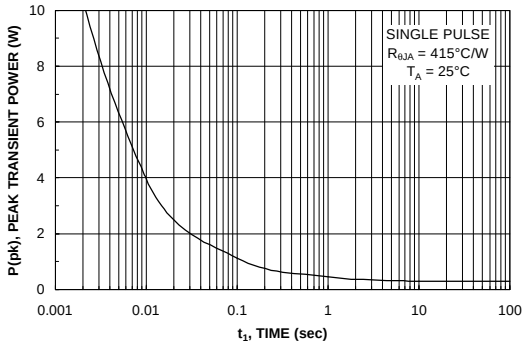


Figure 10. Single Pulse Maximum Power Dissipation.

Typical Characteristics: P-Channel

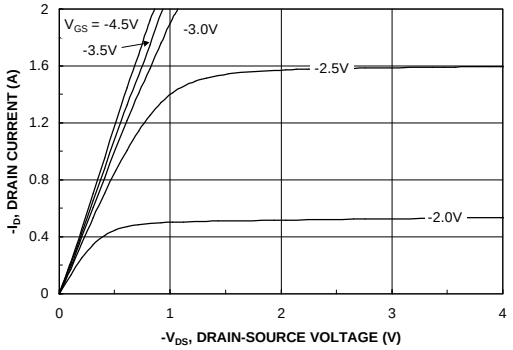


Figure 11. On-Region Characteristics.

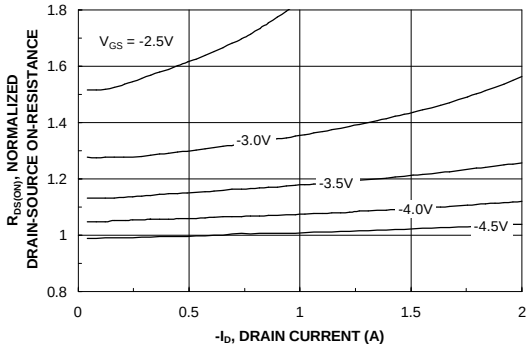


Figure 12. On-Resistance Variation with Drain Current and Gate Voltage.

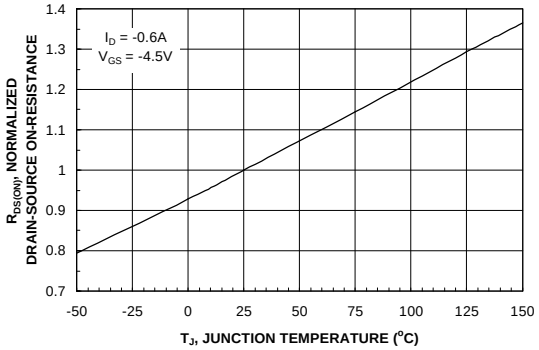


Figure 13. On-Resistance Variation with Temperature.

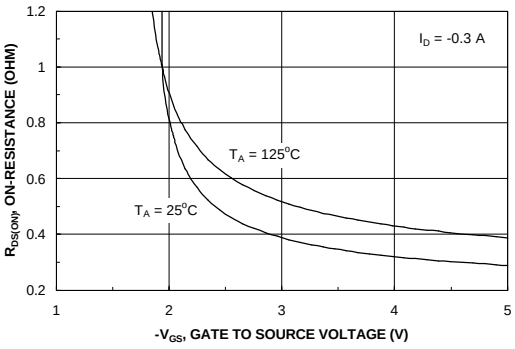


Figure 14. On-Resistance Variation with Gate-to-Source Voltage.

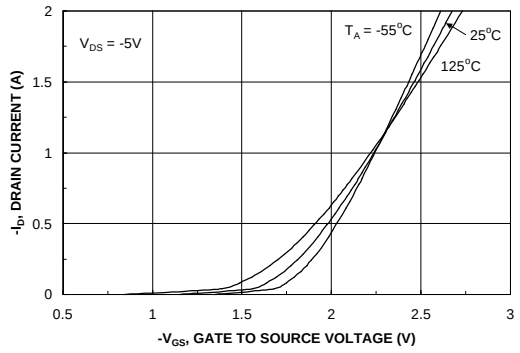


Figure 15. Transfer Characteristics.

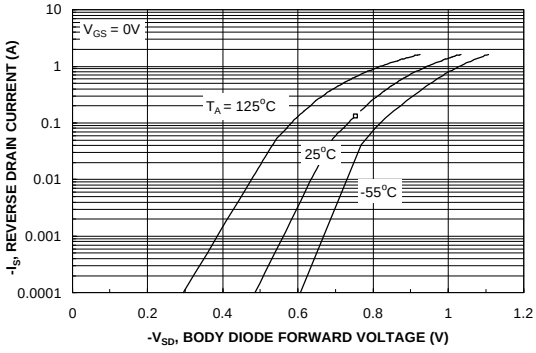


Figure 16. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics: P-Channel

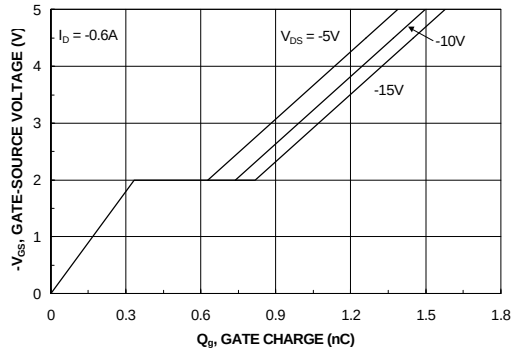


Figure 17. Gate Charge Characteristics.

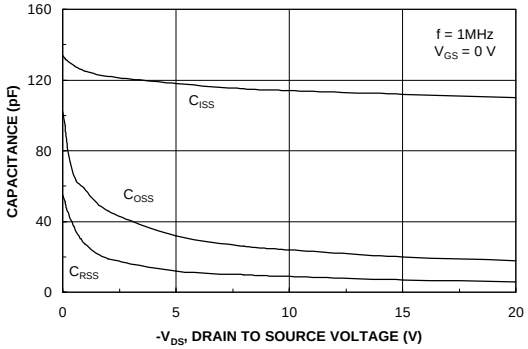


Figure 18. Capacitance Characteristics.

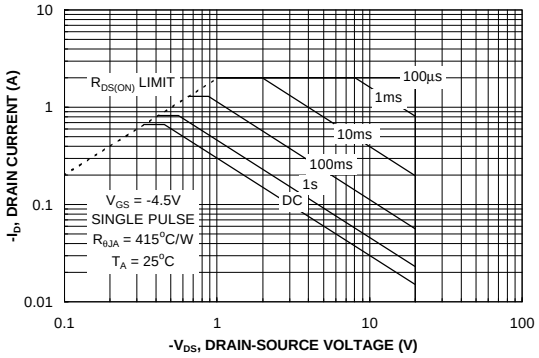


Figure 19. Maximum Safe Operating Area.

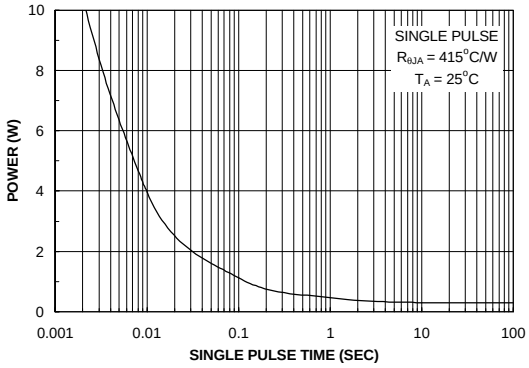


Figure 20. Single Pulse Maximum Power Dissipation.

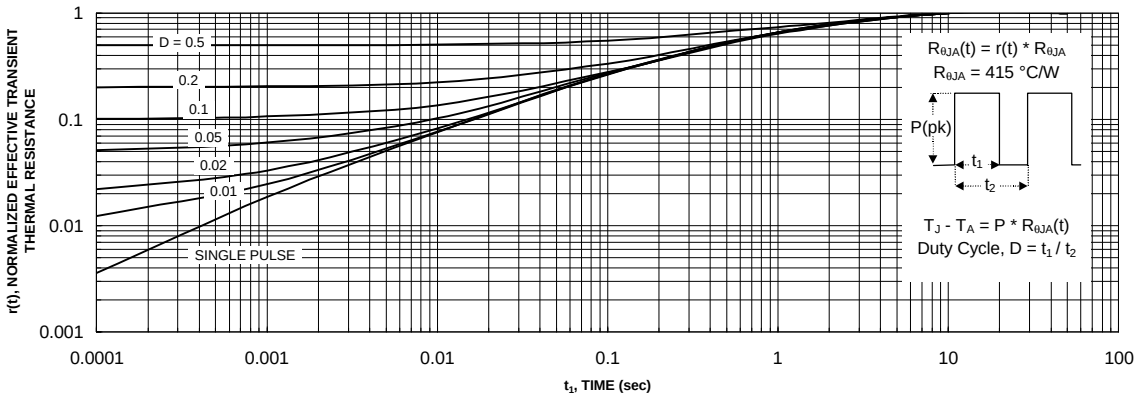


Figure 21. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1.
Transient thermal response will change depending on the circuit board design.

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I76

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FDG6332C

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- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

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«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

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«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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